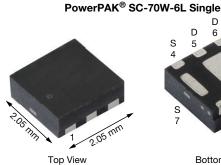
## SQA700CEJW

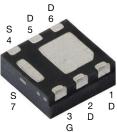
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**Vishay Siliconix** 

# Automotive N-Channel 100 V (D-S) 175 °C MOSFET



Marking Code: Q2XXXX



Bottom View

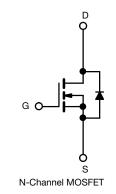
PRODUCT SUMMARY				
V <sub>DS</sub> (V)	100			
$R_{DS(on)} (\Omega)$ at $V_{GS} = 4.5 V$	0.099			
$R_{DS(on)} (\Omega)$ at $V_{GS} = 10 V$	0.079			
I <sub>D</sub> (A)	9			
Configuration	Single			

### **FEATURES**

- TrenchFET<sup>®</sup> power MOSFET
- AEC-Q101 qualified
- Wettable flank terminals
- 100 % R<sub>q</sub> and UIS tested
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912



FREE



ORDERING INFORMATION	
Package	PowerPAK SC-70W-6L
Lead (Pb)-free and halogen-free	SQA700CEJW (for detailed order number please see <u>www.vishay.com/doc?79776</u> )

ABSOLUTE MAXIMUM RATING	<b>GS</b> (T <sub>C</sub> = 25 °C, unless	otherwise noted	)	
PARAMETER	SYMBOL	LIMIT	UNIT	
Drain-source voltage Gate-source voltage		V <sub>DS</sub>	100	
		V <sub>GS</sub>	± 20	V
Continuous drain current	T <sub>C</sub> = 25 °C ª	I	9	
	T <sub>C</sub> = 125 °C	ID	5.2	
Continuous source current (diode conduction) <sup>a</sup>		I <sub>S</sub>	9	А
Pulsed drain current <sup>a</sup>		I <sub>DM</sub>	24	
Single pulse avalanche current	L = 0.1 mH	I <sub>AS</sub>	7.3	
Single pulse avalanche energy		E <sub>AS</sub>	2.66	mJ
Maximum power dissipation	T <sub>C</sub> = 25 °C	P <sub>D</sub>	13.6	W
	T <sub>C</sub> = 125 °C		4.5	vv
Operating junction and storage temperature	perating junction and storage temperature range		-55 to +175	°C
Soldering recommendations (peak temperations)	ature) <sup>d, e</sup>	-	260	C

THERMAL RESISTANCE RATINGS					
PARAMETER		SYMBOL	LIMIT	UNIT	
Junction-to-ambient	PCB mount <sup>c</sup>	R <sub>thJA</sub>	90	°C/W	
Junction-to-case (drain)		R <sub>thJC</sub>	11	0/10	

#### Notes

a. Package limited

See solder profile (<u>www.vishay.com/doc?73257</u>). The PowerPAK SC-70W-6L is a leadless package and features wettable terminals. The end of the lead terminal is plated with tin d.

e. Rework conditions: manual soldering with a soldering iron is not recommended for leadless components

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b. Pulse test; pulse width  $\leq$  300 µs, duty cycle  $\leq$  2 % c. When mounted on 1" square PCB (FR4 material)

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PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
Static					•		
Drain-source breakdown voltage	V <sub>DS</sub>	$V_{GS}$ = 0 V, $I_D$ = 250 $\mu$ A		100	-	-	v
Gate-source threshold voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}$ , $I_D = 250 \mu A$		1.5	2.0	2.5	
Gate-source leakage	I <sub>GSS</sub>	$V_{DS} = 0 V, V_{GS} = \pm 20 V$		-	-	± 100	nA
		$V_{GS} = 0 V$	V <sub>DS</sub> = 100 V	-	-	1	μA
Zero gate voltage drain current	I <sub>DSS</sub>	$V_{GS} = 0 V$	V <sub>DS</sub> = 100 V, T <sub>J</sub> = 125 °C	-	-	50	
		$V_{GS} = 0 V$	V <sub>DS</sub> = 100 V, T <sub>J</sub> = 175 °C	-	-	250	
On-state drain current <sup>a</sup>	I <sub>D(on)</sub>	V <sub>GS</sub> = 10 V	$V_{DS} \ge 5 V$	10	-	-	Α
		V <sub>GS</sub> = 10 V	I <sub>D</sub> = 3 A	-	0.056	0.079	-
		V <sub>GS</sub> = 10 V	I <sub>D</sub> = 3 A, T <sub>J</sub> = 125 °C	-	-	0.077	
Drain-source on-state resistance <sup>a</sup>	R <sub>DS(on)</sub>	V <sub>GS</sub> = 10 V	I <sub>D</sub> = 3 A, T <sub>J</sub> = 175 °C	-	-	0.090	Ω
		V <sub>GS</sub> = 4.5 V	I <sub>D</sub> = 3 A	-	0.070	0.099	
Forward transconductance b	g <sub>fs</sub>	V <sub>DS</sub>	= 15 V, I <sub>D</sub> = 3 A	-	9.0	-	S
Dynamic <sup>b</sup>					•	•	•
Input capacitance	C <sub>iss</sub>		V <sub>DS</sub> = 25 V, f = 1 MHz	-	271	380	pF
Output capacitance	Coss	$V_{GS} = 0 V$		-	140	200	
Reverse transfer capacitance	C <sub>rss</sub>			-	12	17	
Total gate charge <sup>c</sup>	Qg			-	6.2	9.5	nC
Gate-source charge <sup>c</sup>	Q <sub>gs</sub>	$V_{GS} = 10 V$	$V_{DS} = 50 \text{ V}, \text{ I}_{D} = 2 \text{ A}$	-	1.2	-	
Gate-drain charge <sup>c</sup>	Q <sub>gd</sub>			-	1.3	-	
Gate resistance	Rg	f = 1 MHz		0.5	1.1	1.6	Ω
Turn-on delay time <sup>c</sup>	t <sub>d(on)</sub>	$V_{DD} = 50 \text{ V}, \text{ R}_{\text{L}} = 25 \Omega$ $\text{I}_{\text{D}} \cong 2 \text{ A}, \text{ V}_{\text{GEN}} = 10 \text{ V}, \text{ R}_{\text{g}} = 1 \Omega$		-	6.0	10	
Rise time <sup>c</sup>	t <sub>r</sub>			-	4	7	ns
Turn-off delay time <sup>c</sup>	t <sub>d(off)</sub>			-	14	22	
Fall time <sup>c</sup>	t <sub>f</sub>			-	5	8	
Source-Drain Diode Ratings and Character	eristics <sup>b</sup>	•					
Pulsed current <sup>a</sup>	I <sub>SM</sub>			-	-	24	Α
Forward voltage	V <sub>SD</sub>	$I_F = 4.5 \text{ A}, V_{GS} = 0 \text{ V}$		-	0.86	1.2	V
Body diode reverse recovery time	t <sub>rr</sub>			-	24	48	ns
Body diode reverse recovery charge	Q <sub>rr</sub>	I <sub>F</sub> = 2 A, di/dt = 100 A/μs		-	20	40	nC
Reverse recovery fall time	ta			-	15	-	
Reverse recovery rise time	t <sub>b</sub>			-	9	-	ns
Body diode peak reverse recovery current	I <sub>RM(REC)</sub>			-	-1.5	-	Α

#### Notes

a. Pulse test; pulse width  $\leq$  300 µs, duty cycle  $\leq$  2 %

b. Guaranteed by design, not subject to production testing

c. Independent of operating temperature

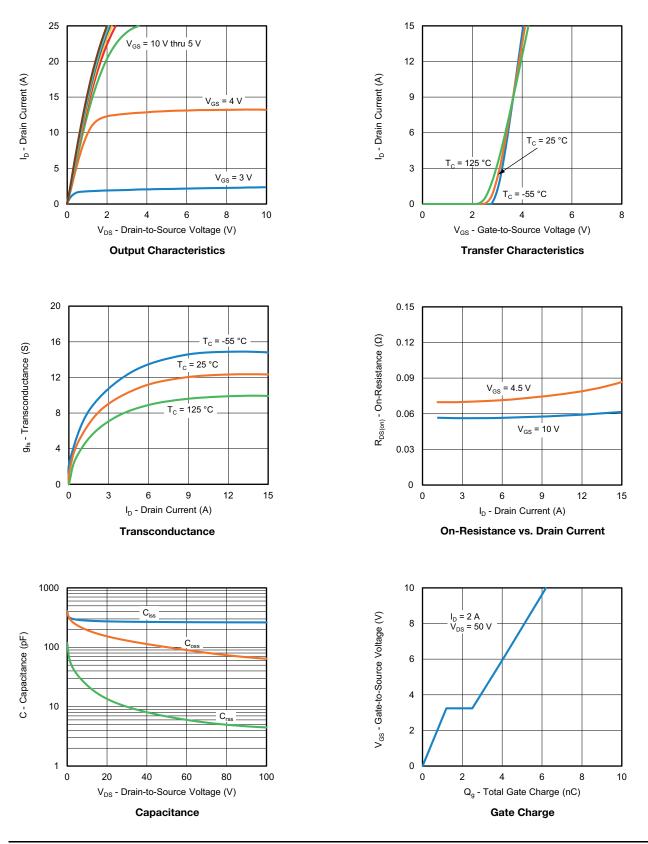
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

2



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## **TYPICAL CHARACTERISTICS** ( $T_A = 25 \text{ °C}$ , unless otherwise noted)



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3

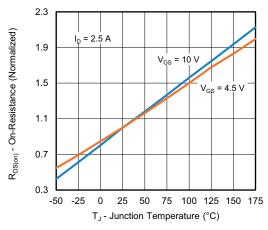
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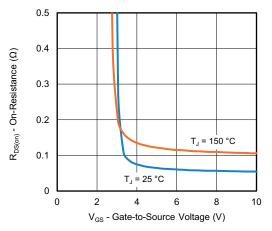


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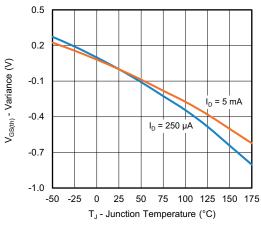
### TYPICAL CHARACTERISTICS (T<sub>A</sub> = 25 °C, unless otherwise noted)



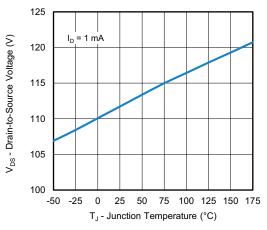
**On-Resistance vs. Junction Temperature** 



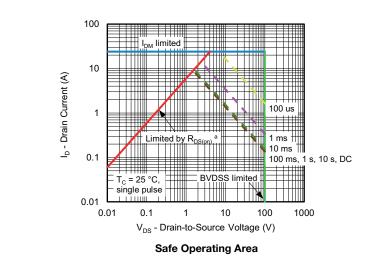
**On-Resistance vs. Gate-to-Source Voltage** 

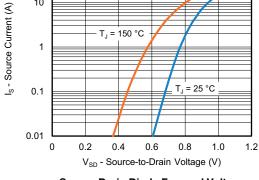


**Threshold Voltage** 



Drain Source Breakdown vs. Junction Temperature





Source Drain Diode Forward Voltage

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100

10

4

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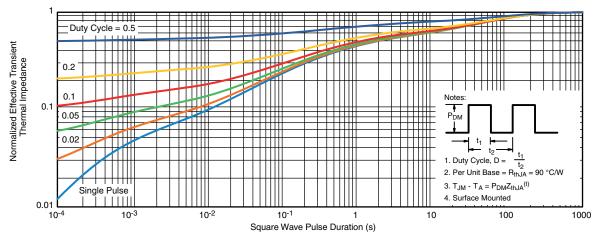
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### **THERMAL RATINGS** (T<sub>A</sub> = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Case

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